

# SEMICONDUCTOR TECHNICAL DATA

# SMCB34

#### SCHOTTKY BARRIER TYPE DIODE

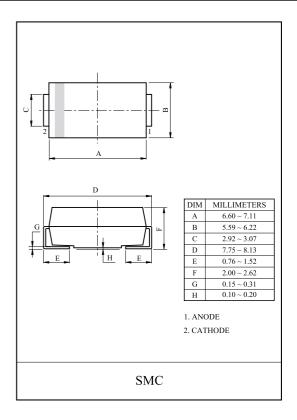
## SWITCHING TYPE POWER SUPPLY APPLICATIONS.

#### **FEATURES**

- · Low Profile Surface Mount Package.
- · Low Power Loss, High Efficiency.
- For Use in Low Voltage, High Frequency inverters, Free Wheeling, and Polarity Protection Applications.

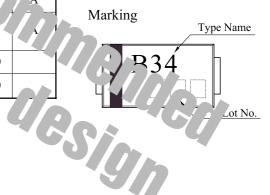
#### APPLICATION

- · Switching Power Supply.
- · DC/DC Converter.
- · Home Appliances, Office Equipment.
- · Telecommunication.
- · Qualified to AEC-Q101.



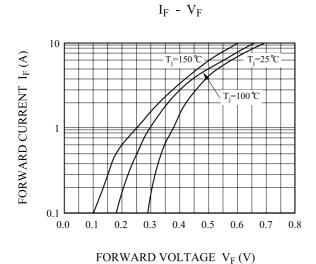
## MAXIMUM RATING (Ta=25

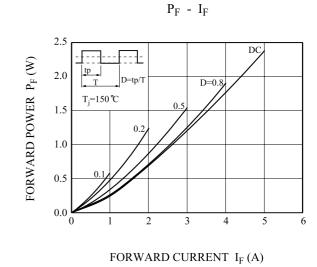
CHARACTERISTIC	YMBO'	RATING	UNIT
Maximum Repetitive Peak Reve - Voltage	V <sub>RK</sub>	200	V
Average Output Rectitifed Cu. an	I <sub>O</sub>		A
Peak One Cycle Surge Forward Curren		100	
(Non-Repetitive 60Hz)	S	100	
Junction Temperature	-j	.0 150	
Storage Temperature Range	$T_{stg}$	4 150	

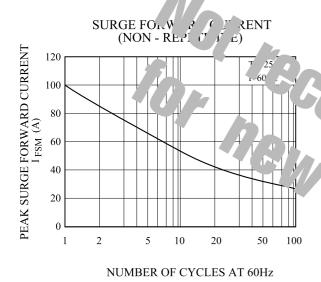


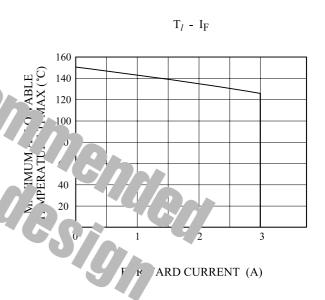
# ELECTRICAL CHARACTERISTICS (Ta=25 )

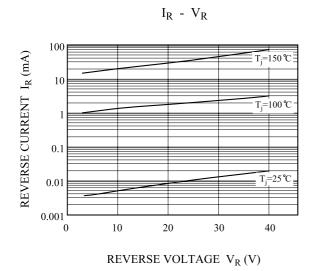
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage	$V_{\rm FM}$	I <sub>FM</sub> =3A	-	-	0.5	V
Repetitive Peak Reverse Current I <sub>RRM</sub>	I	V <sub>RRM</sub> =Rated, Tj=25	-	-	0.1	mA
	¹RRM	V <sub>RRM</sub> =Rated, Tj=100	-	-	10	mA
Total Capacitance	$C_{T}$	V <sub>R</sub> =4V, f=1MHz	-	-	250	pF
Thermal Resistance	R <sub>th(j-1)</sub>	Junction to lead	-	-	10	/W
	R <sub>th(j-a)</sub>	Junction to ambient	-	-	50	/W











2012. 5. 8